

SKiiP 25NAB065V1



MiniSKiiP® 2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 25NAB065V1

Features

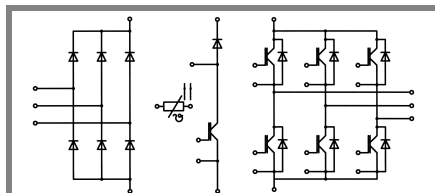
- Ultrafast NPT IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications

- Inverter up to 10 kVA
- Typical motor power 4,0 kW

Remarks

- V_{CEsat} , V_F = chip level value



NAB

Absolute Maximum Ratings		T _s = 25 °C, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter, Chopper			
V _{CES}	T _s = 25 (70) °C t _p ≤ 1 ms	600	V
I _C		38 (28)	A
I _{CRM}		60	A
V _{GES}		± 20	V
T _j		- 40 ... + 150	°C
Diode - Inverter, Chopper			
I _F	T _s = 25 (70) °C t _p ≤ 1 ms	40 (30)	A
I _{FRM}		60	A
T _j		- 40 ... + 150	°C
Diode - Rectifier			
V _{RRM}	T _s = 70 °C t _p = 10 ms, sin 180 °, T _j = 25 °C t _p = 10 ms, sin 180 °, T _j = 25 °C	800	V
I _F		46	A
I _{FSM}		370	A
i ² t		680	A ² s
T _j		- 40 ... + 150	°C
I _{tRMS}		per power terminal (20 A / spring)	60
T _{stg}	T _{op} ≤ T _{stg}	- 40 ... + 125	°C
V _{isol}	AC, 1 min.	2500	V

Characteristics		$T_s = 25\text{ °C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
V_{CEsat}	$I_{Cnom} = 30\text{ A, } T_j = 25\text{ (125) °C}$		2 (2,2)	2,5 (2,7)	V
$V_{GE(th)}$	$V_{GE} = V_{CE}, I_C = 0,5\text{ mA}$	3	4	5	V
$V_{CE(TO)}$	$T_j = 25\text{ (125) °C}$		1,2 (1,1)	1,3 (1,2)	V
r_T	$T_j = 25\text{ (125) °C}$		27 (37)	40 (50)	mΩ
C_{ies}	$V_{CE} = 25\text{ V, } V_{GE} = 0\text{ V, } f = 1\text{ MHz}$		1,5		nF
C_{oes}	$V_{CE} = 25\text{ V, } V_{GE} = 0\text{ V, } f = 1\text{ MHz}$		0,45		nF
C_{res}	$V_{CE} = 25\text{ V, } V_{GE} = 0\text{ V, } f = 1\text{ MHz}$		0,35		nF
$R_{th(j-s)}$	per IGBT		1,05		K/W
$t_{d(on)}$	under following conditions		20		ns
t_r	$V_{CC} = 300\text{ V, } V_{GE} = \pm 15\text{ V}$		20		ns
$t_{d(off)}$	$I_{Cnom} = 30\text{ A, } T_j = 125\text{ °C}$		185		ns
t_f	$R_{Gon} = R_{Goff} = 20\text{ Ω}$		15		ns
E_{on}	inductive load		1		mJ
E_{off}			0,6		mJ
Diode - Inverter, Chopper					
$V_F = V_{EC}$	$I_{Fnom} = 30\text{ A, } T_j = 25\text{ (125) °C}$		1,5 (1,5)	1,8 (1,8)	V
$V_{(TO)}$	$T_j = 25\text{ (125) °C}$		1 (0,9)	1,1 (1)	V
r_T	$T_j = 25\text{ (125) °C}$		18 (20)	23 (27)	mΩ
$R_{th(j-s)}$	per diode		1,5		K/W
I_{RRM}	under following conditions		45		A
Q_{rr}	$I_{Fnom} = 30\text{ A, } V_R = 300\text{ V}$		3,1		μC
E_{rr}	$V_{GE} = 0\text{ V, } T_j = 125\text{ °C}$ $di_F/dt = 2040\text{ A/μs}$		0,8		mJ
Diode - Rectifier					
V_F	$I_{Fnom} = 25\text{ A, } T_j = 25\text{ °C}$		1,1		V
$V_{(TO)}$	$T_j = 150\text{ °C}$		0,8		V
r_T	$T_j = 150\text{ °C}$		13		mΩ
$R_{th(j-s)}$	per diode		1,25		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25\text{ (100) °C}$		1000(1670)		Ω
Mechanical Data					
w			65		g
M_s	Mounting torque	2		2,5	Nm

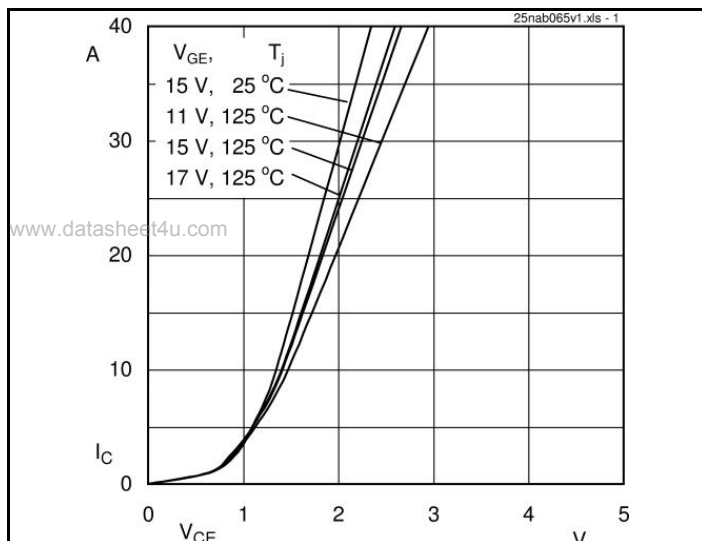


Fig. 1 Typ. output characteristic

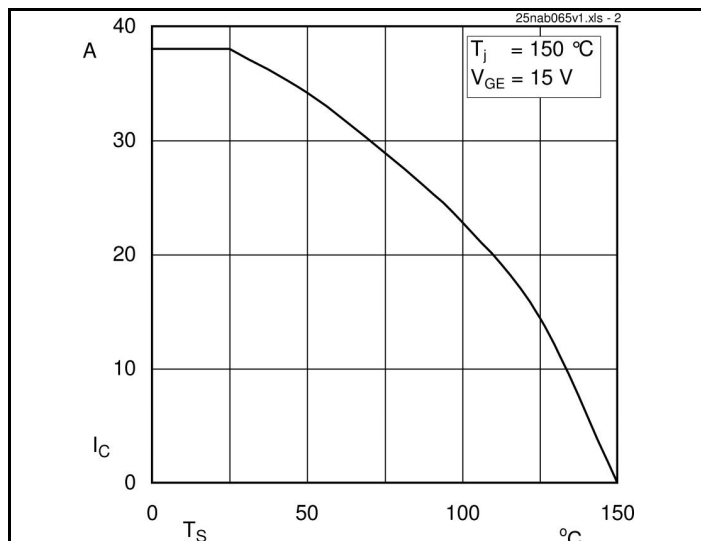


Fig. 2 Typ. rated current vs. temperature

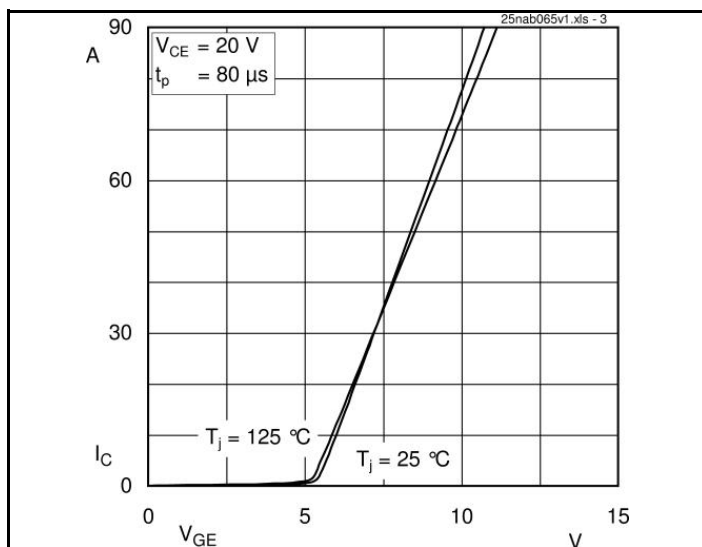


Fig. 3 Typ. transfer characteristic

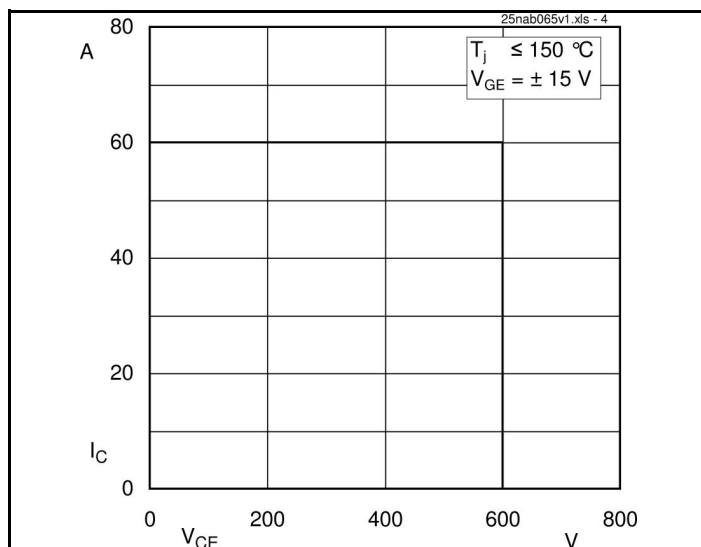


Fig. 4 Reverse bias safe operating area

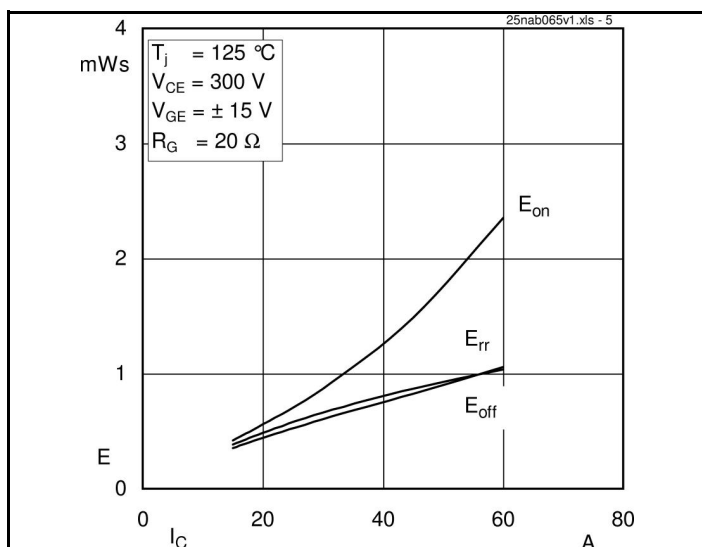


Fig. 5 Typ. Turn-on /-off energy = $f(I_C)$

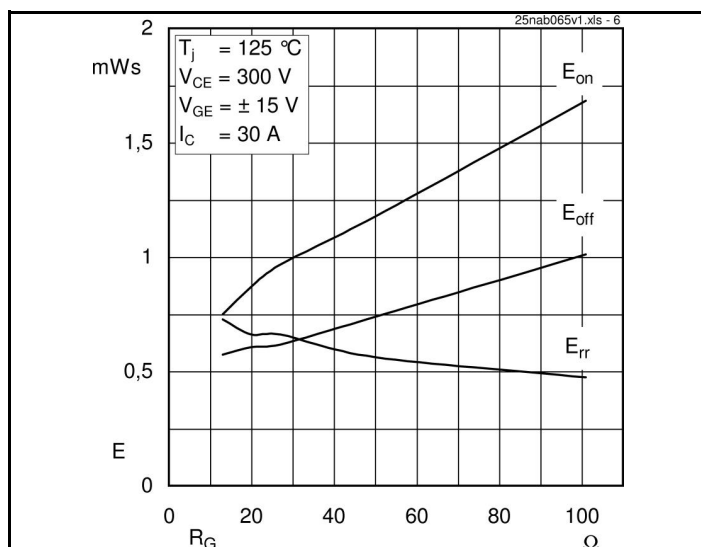
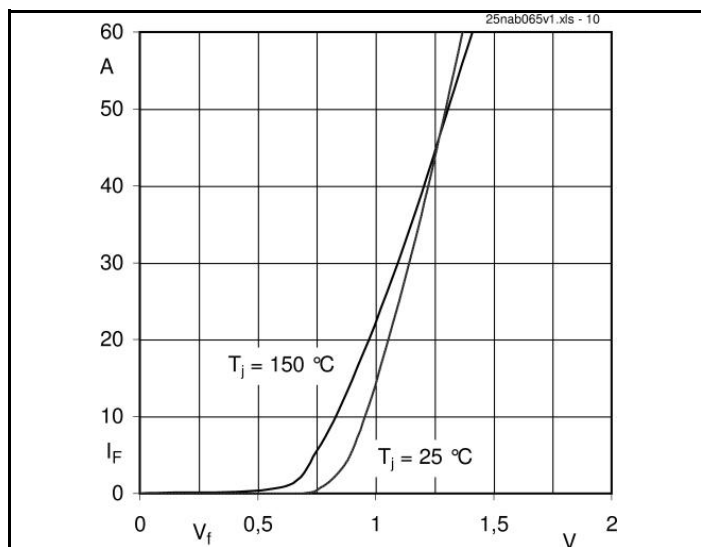
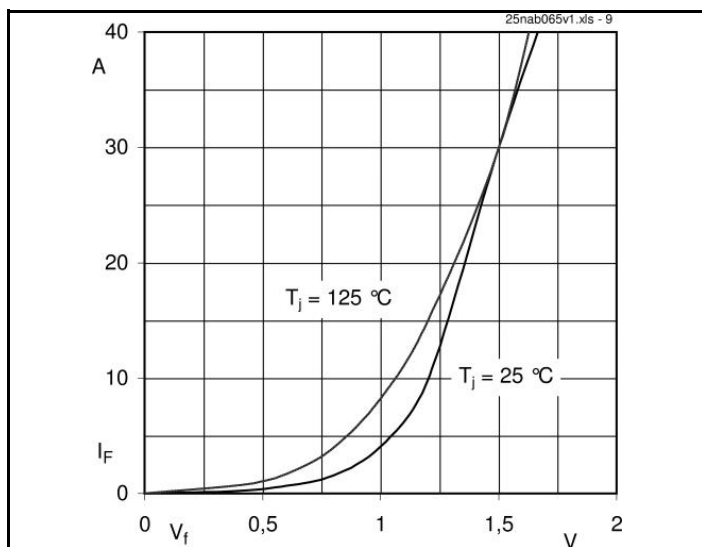
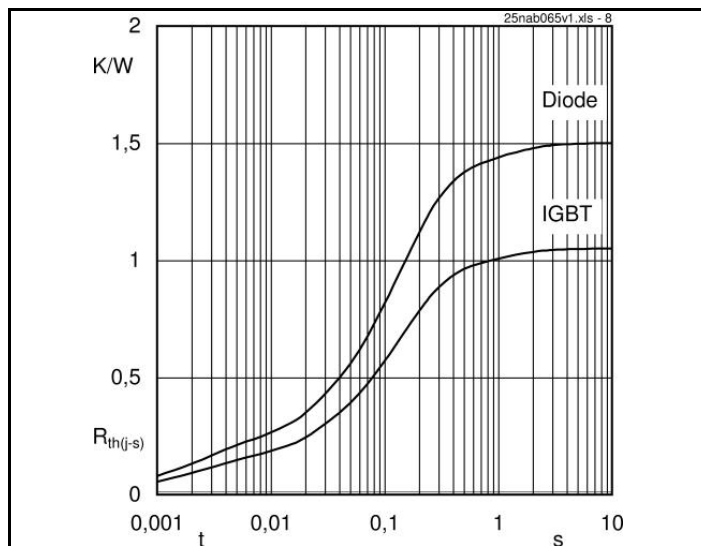
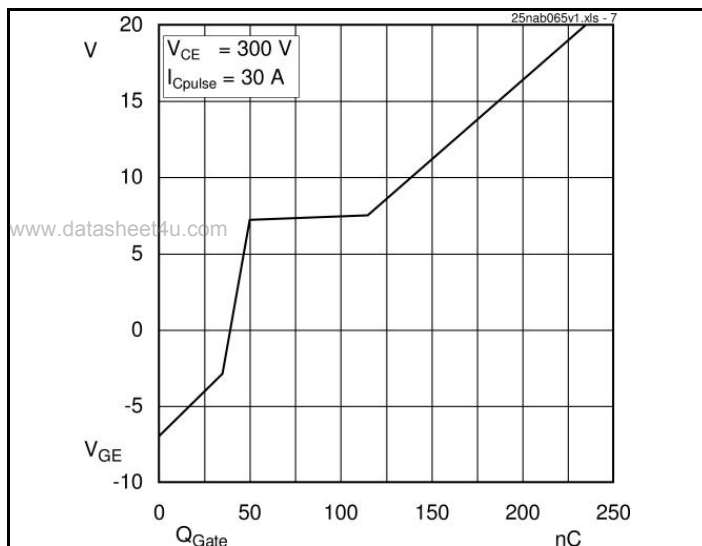
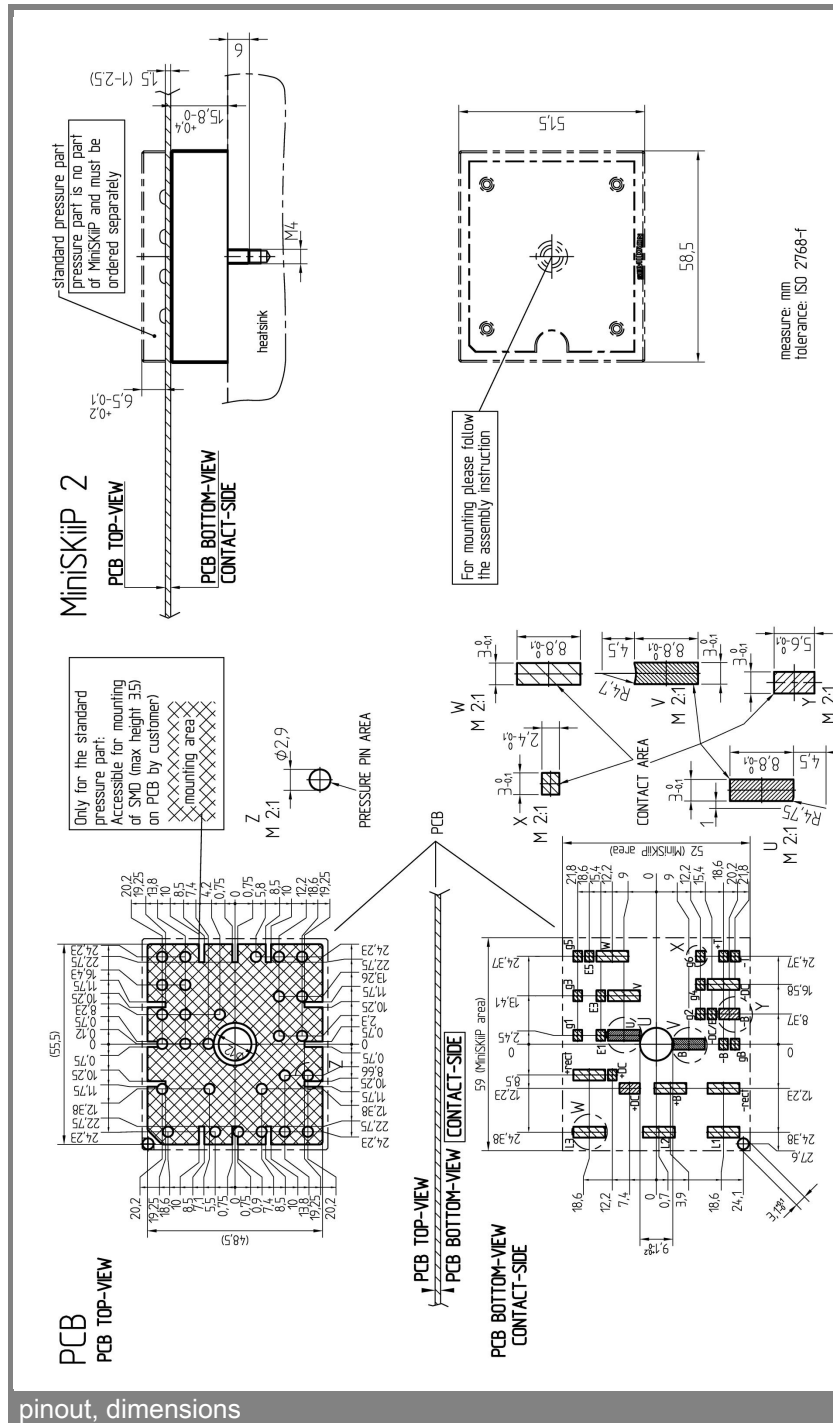
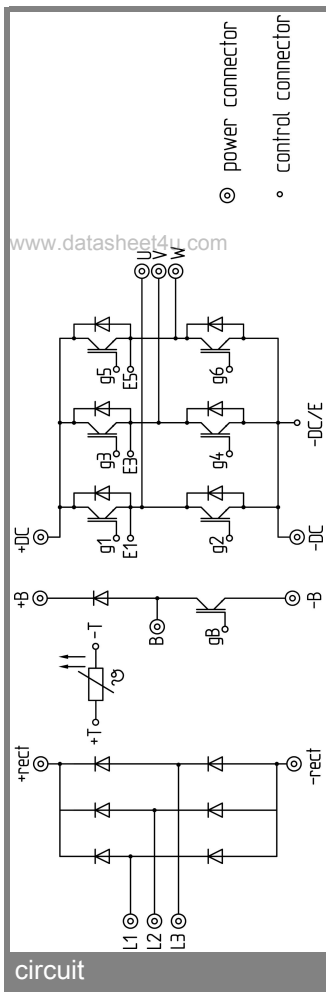


Fig. 6 Typ. Turn-on /-off energy = $f(R_G)$





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